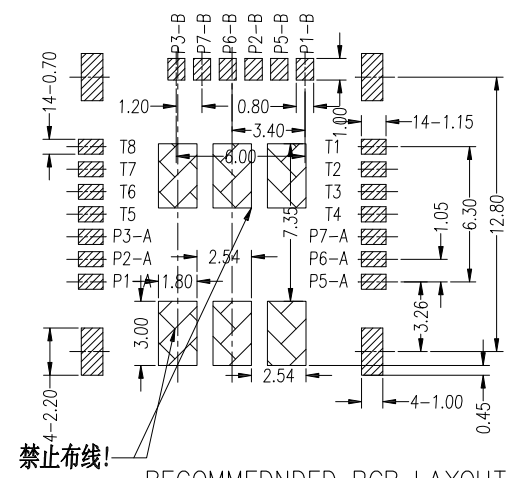
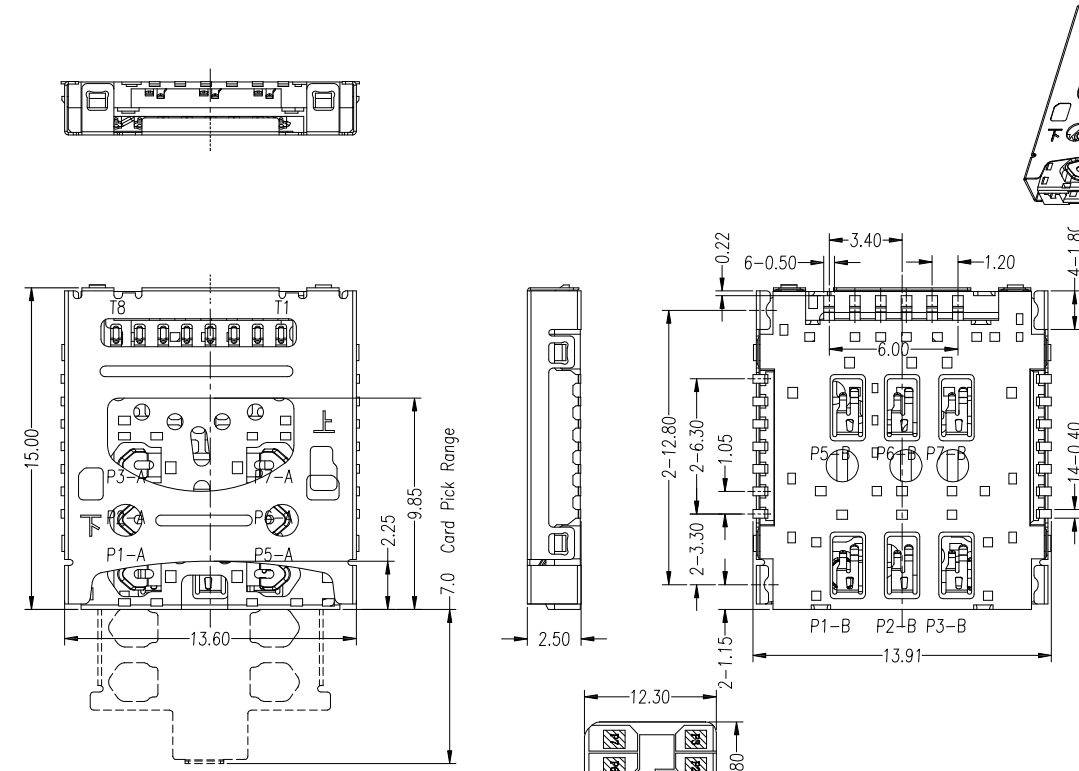


* All Raw Material, Manufacturing, Plating process comply with ROHS



禁止布线!
TOL.: ±0.05

- Note:
- Specification:
 - Voltage Rating: 50V
 - Current rating: 1 A Max.
 - Dielectric withstanding voltage: 250 V(ac) for 1 min.
 - Contact resistance: 50 mΩ Max.
 - Insulation resistance: 1000 MΩ Min.
 - Durability: 3000 Cycles
 - Temperature range: -30°C~80°C

NanoSim卡 Pin脚定义 TF卡 Pin脚定义

8P	描述	No.	描述
P1	Vcc	T1	DAT2
P2	RST	T2	CD/DAT3
P3	CLK	T3	CMD
--	Reserved	T4	VDD
P5	GND	T5	CLK
P6	Vpp	T6	Vss
P7	I/O	T7	DAT0
--	Reserved	T8	DAT1

4	Tray	Sus301 T=0.12	None
3	Shell	Sus301 T=0.12	50u"Min. Ni underplated all;1~3u"Min.Au plated solder Legs
2	Contact	C5210 T=0.10	50u"Min. Ni underplated all;1~3u"Min.Au plated Contact Area&Solder tail
1	Housing	LCP S475;Black	UL 94V-0
No.	Part name	Material	FINISH

深圳市鑫南天科技有限公司
Shen zhen Xin Nan Tian Technology Co., Ltd

DIMENSIONS UNIT: mm UNLESS OTHERWISE SPECIFIABLE DIMENSION TOLERANCE X.X: ± 0.38 X.XX: ± 0.25 X.XXX: ± 0.10 ANGULAR: ± 1°	PRODUCT NAME : 三选二 (nano sim+nano sim +micro sd) PRODUCT NO. : XNT-NSM-11735 DRAWING NO. : XNT-1735	DRAWING: COCO CHECK: JANY APPROVED: JEFF	DATE: 2017/09/22 DATE: 2017/09/22 DATE: 2017/09/22
		SCALE: 1:1 DWG ID: C D REV.: A PAGE: 1 OF 1	

REVISION NO.	ECR NO.	DESCRIPTION	MARK	DATE
1				
2				
3				